











Documents

BUF20800-Q1

SBOS571A - AUGUST 2011 - REVISED NOVEMBER 2017

## **BUF20800-Q1 18-Channel Programmable Gamma Voltage Generator** with Two Programmable VCOM Channels

#### **Features**

- **Qualified for Automotive Applications**
- AEC-Q100 Qualified With the Following Results:
  - Device Temperature Grade 1
  - Device HBM ESD Classification Level 2
  - Device CDM ESD Classification Level C4
- Low Supply Current: 900 μA/ch
- Analog Supply Voltage: 7 V to 18 V
- Digital Supply Voltage: 2.0 V to 5.5 V
- 18-Channel Gamma Correction
- 2-Channel Programmable V<sub>COM</sub>: 50 mA I<sub>OUT</sub>
- 10-Bit Resolution
- Rail-to-Rail Output
- I<sup>2</sup>C Interface
  - 3.4 MHz High-Speed Mode
- Demo Board and Software Available

## **Applications**

- Replaces Resistor-Based Gamma Solutions
- **TFT-LCD Reference Drivers**
- Dynamic Gamma Control

## Description

The BUF20800-Q1 is a programmable voltage reference generator designed for gamma correction in TFT-LCD panels. It provides 18 programmable outputs for gamma correction and two channels for V<sub>COM</sub> adjustment, each with 10-bit resolution.

All channels are programmable using an I<sup>2</sup>C interface that supports high-speed data transfers up to 3.4 MHz.

This programmability replaces the traditional, time consuming process of changing resistor values to optimize the various gamma voltages and allows designers to determine the correct gamma voltages for a panel very quickly. Required changes are easily implemented without hardware changes.

The BUF20800-Q1 uses TI's latest, small-geometry analog CMOS process, which makes it a very competitive choice for full production, not just evaluation.

For lower channel count, please contact your local sales or marketing representative.

The BUF20800-Q1 is available in an HTSSOP-38 package withPowerPAD™. It is specified from -40°C to +105°C.

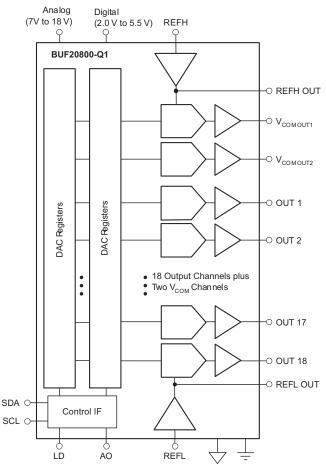
#### **Device Information** (1)

PART NUMBER	PACKAGE	BODY SIZE (NOM)
BUF20800-Q1	HTSSOP (38)	9.80 mm × 9.60 mm

#### **Related Products**

FEATURES	PRODUCT
12-Channel Programmable Buffer, 10-Bit	BUF12800
Programmable V <sub>COM</sub>	BUF01900
11-, 6-, 4-Channel Gamma Correction Buffer, 18V Supply	BUFxx704
High-Speed V <sub>COM</sub> , 1 and 2 Channels	SN10501
Complete LCD DC/DC Solution	TPS65100

#### Simplified Block Diagram



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For all available packages, see the orderable addendum at the end of the data sheet.



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#### 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

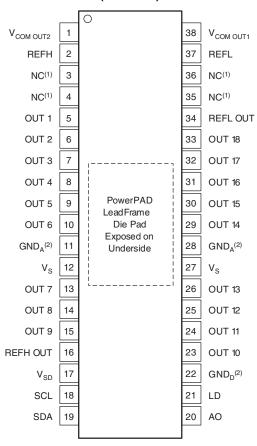
#### Changes from Original (August 2011) to Revision A

**Page** 



## 5 Pin Configuration and Functions

#### DCP Package BUF20800-Q1 HTSSOP 38 Pins (TOP VIEW)



- (1) NC denotes no connection
- (2) GND<sub>D</sub> and GND<sub>A</sub> are internally connected and must be at the same voltage potential.

#### **Pin Functions**

F	PIN		DECODINE	
NAME	NO.	· I/O	DESCRIPTION	
A0	20	I	Two-wire serial interface address select pin	
CND	28		Analog ground Must be connected to digital ground CND	
GND <sub>A</sub>	11	_	Analog ground. Must be connected to digital ground GND <sub>D</sub> .	
GND <sub>D</sub>	22	_	Digital ground. Must be connected to analog ground GND <sub>A</sub> .	
LD	21		Output latch pin	
	3			
NC	4		No connection I can this min floating	
NC	35	_	No connection. Leave this pin floating.	
	36			
OUT1	5	0	DAC output 1	
OUT2	6	0	DAC output 2	
OUT3	7	0	DAC output 3	
OUT4	8	0	DAC output 4	
OUT5	9	0	DAC output 5	

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#### Pin Functions (continued)

PIN			DECODURE	
NAME	NO.	I/O	DESCRIPTION	
OUT6	10	0	DAC output 6	
OUT7	13	0	DAC output 7	
OUT8	14	0	DAC output 8	
OUT9	15	0	DAC output 9	
OUT10	23	0	DAC output 10	
OUT11	24	0	DAC output 11	
OUT12	25	0	DAC output 12	
OUT13	26	0	DAC output 13	
OUT14	29	0	DAC output 14	
OUT15	30	0	DAC output 15	
OUT16	31	0	DAC output 16	
OUT17	32	0	DAC output 17	
OUT18	33	0	DAC output 18	
REFH	2	I	Reference voltage REFH input	
REFH OUT	16	0	Reference voltage REFH output	
REFL	37	I	Reference voltage REFL input	
REFL OUT	34	0	Reference voltage REFL output	
SCL	18	I	Serial clock input; open drain.	
SDA	19	I/O	Serial data I/O; open drain.	
VCOMOUT1	38	0	VCOM channel 1	
VCOMOUT2	1	0	VCOM channel 2	
VS	12 27	- 1	Analog supply	
VSD	17	ı	Digital supply	

## 6 Specifications

## 6.1 Absolute Maximum Ratings (1)

over operating free-air temperature range (unless otherwise noted).

	PARAMETER		VALUE	UNIT
Vs	Supply voltage		19	V
$V_{SD}$	Supply voltage		6	V
	Circulation of terminals CCL CDA ACLD	Voltage	-0.5 to 6	V
	Signal input terminals, SCL, SDA, AO, LD	Current	±10	mA
	Output Short-Circuit (2)		Continuous	
T <sub>A</sub>	T <sub>A</sub> Operating temperature		-40 to +105	°C
T <sub>stg</sub>	T <sub>stq</sub> Storage temperature		-65 to +150	°C
TJ	Junction temperature		125	°C
	Latch-up per JESD78B		Class 1	

<sup>(1)</sup> Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.

(2) Short-circuit to ground, one channel at a time.

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## 6.2 ESD Ratings

			VALUE	UNIT
	Human-body model (HBM), per AEC Q100-002 (1)	±2000	\/	
V <sub>(ESD)</sub>	Electrostatic discharge	Charged-device model (CDM), per AEC Q100-011	±750	V

<sup>(1)</sup> AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

## 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM MAX	UNIT
VS	Analog supply	7	18	V
VSD	Digital supply	2	5.5	V
REFH	Reference high	4	VS - 0.2	V
REFL	Reference low	GND + 0.2	VS - 4	V
T <sub>A</sub>	Operating ambient temperature	-40	105	°C
TJ	Operating junction temperature		125	°C

#### 6.4 Thermal Information

		BUF20800-Q1	
	THERMAL METRIC (1)	DCP Package (HTSSOP Family)	UNIT
		38 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	28.8	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	21.4	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	7.6	°C/W
ΨЈТ	Junction-to-top characterization parameter	0.3	°C/W
ΨЈВ	Junction-to-board characterization parameter	7.7	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	1.1	°C/W

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

Product Folder Links: BUF20800-Q1



#### 6.5 Electrical Characteristics

At  $T_A = 25^{\circ}$ C,  $V_C = 18$  V,  $V_{CD} = 5$  V,  $R_C = 1.5$  kO connected to ground, and  $C_C = 200$  pF, unless otherwise noted

- /\		= 1.5 k $\Omega$ connected to ground, and $C_L$ = 200 pF,	BUF20800-Q1			
	PARAMETER	CONDITIONS		MIN TYP MAX		
		CONDITIONS	IVIIN	ITP	WAX	UNIT
ANAL	OG GAMMA BUFFER CHANNELS	0 : 40 4 1/ 47 0 1/ 4000				
	OUT 1-9 output swing: high	Sourcing 10 mA, $V_{REFH}$ = 17.8 V, Code 1023, $T_A$ = -40°C to +105°C	17.7	17.8		V
	OUT 10−18 output swing: high	Sourcing 10 mA, $V_{REFH}$ = 17.8 V, Code 978, $T_A = -40^{\circ}\text{C}$ to +105°C	16.8	17.2		
	OUT 1-9 output swing: low	Sinking 10 mA, $V_{REFL} = 0.2 \text{ V}$ , Code 32, $T_A = -40 ^{\circ}\text{C}$ to $+105 ^{\circ}\text{C}$		0.6	1.0	V
	OUT 10-18 output swing: low	Sinking 10 mA, $V_{REFL}$ = 0.2 V, Code 00, $T_A$ = -40°C to +105°C		0.2	0.4	V
	VCOM buffer output swing: high	Sourcing 50 mA, $V_{REFH}$ =17.8 V, $T_A = -40^{\circ}\text{C}$ to +105°C	13	15.5		٧
	VCOM buffer output swing: low	Sinking 50 mA, $V_{REFL} = 0.2 \text{ V}$ , $T_A = -40^{\circ}\text{C} \text{ to } +105^{\circ}\text{C}$		1	2.0	٧
0	Output current (1)	All Channels, Code 512, Sinking/Sourcing	40	45		mA
NL	Integral nonlinearity	No Load, V <sub>REFH</sub> = 17 V, V <sub>REFL</sub> = 1 V		0.3	1.5	Bits
DNL	Differential nonlinearity	No Load, V <sub>REFH</sub> = 17 V, V <sub>REFL</sub> = 1 V		0.3	1	Bits
	Gain error			0.12		%
D	Program to out delay			5		μS
		No Load, V <sub>REFH</sub> = 17 V, V <sub>REFL</sub> = 1 V		±20	±50	mV
	Output accuracy	No Load, $V_{REFH} = 17 \text{ V}$ , $V_{REFL} = 1 \text{ V}$ , $V_{A} = -40 \text{ °C}$ to $+105 \text{ °C}$		±25		mV
RI <sub>NH</sub>	Input resistance at V <sub>REFH</sub> and V <sub>REFL</sub>	*		100		ΜΩ
REG	Load regulation, All References	$V_{OUT} = V_S/2$ , $I_{OUT} = 5 \text{ mA to } -5 \text{ mA Step}$		0.5	1.5	mV/m/
	40 mA, All Channels	$V_{OUT} = V_S/2$ , $I_{SINKING} = 40 \text{ mA}$ , $I_{SOURCING} = 40 \text{ mA}$		0.5	1.5	mV/m/
ANAL	OG POWER SUPPLY					
V <sub>S</sub>	Operating range		7		18	V
		No Load		18	28	mA
s	Total analog supply current	Outputs at Reset Values, No Load, Two-Wire Bus Inactive, $T_A = -40^{\circ}\text{C} \text{ to } +105^{\circ}\text{C}$			28	mA
DIGIT	AL					
V <sub>IH</sub>	Logic 1 input voltage		0.7 × V <sub>SD</sub>			V
V <sub>IL</sub>	Logic 0 input voltage				0.3 × V <sub>SD</sub>	V
/ <sub>OL</sub>	Logic 0 output voltage	I <sub>SINK</sub> = 3 mA		0.15	0.4	V
	Input leakage			±0.01	±10	μΑ
		Standard/Fast Mode, T <sub>A</sub> = -40°C to +105°C			400	kHz
CLK	Clock frequency	High-Speed Mode, T <sub>A</sub> = -40°C to +105°C			3.4	MHz
DIGIT	AL POWER SUPPLY		1		1	
V <sub>SD</sub>	Operating range		2.0		5.5	V
		Outputs at Reset Values, No Load, Two-Wire Bus Inactive		25	50	μА
SD	Digital supply current <sup>(2)</sup>	Outputs at Reset Values, No Load, Two-Wire Bus Inactive, $T_A = -40^{\circ}\text{C} \text{ to } +105^{\circ}\text{C}$		100		μА
ГЕМР	ERATURE RANGE					
	Operating temperature range	Junction Temperature < +125°C	-40		+105	°C
	Storage temperature range		-65		+150	°C
JA	Thermal resistance, HTSSOP-38: Junction-to-Ambient			30		°C/W
Jc	Thermal resistance, HTSSOP-38: Junction-to-Case			15		°C/W

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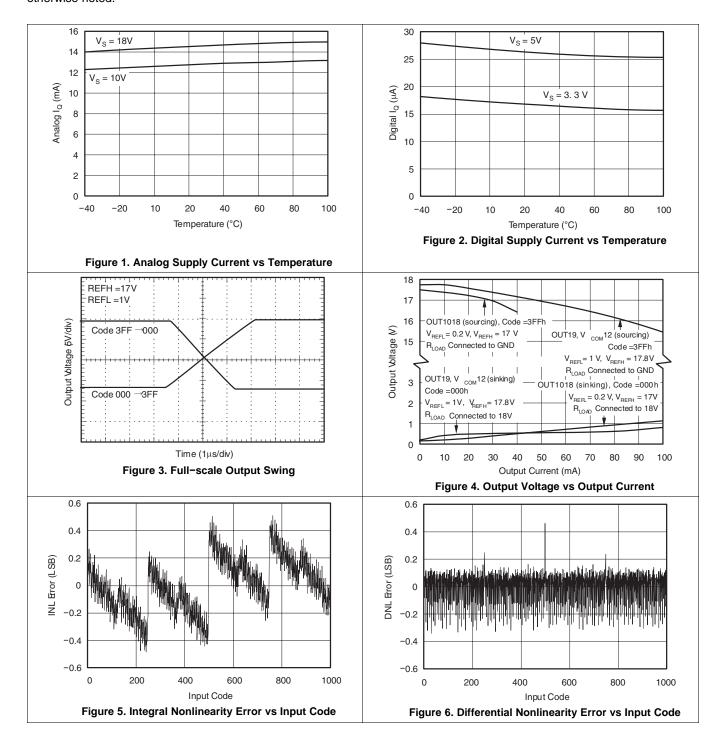
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See typical characteristic graph Output Voltage vs Output Current See typical characteristic graph Digital Supply Current vs Temperature



## 6.6 Typical Characteristics

At  $T_A$  = 25°C,  $V_S$  = 18 V,  $V_{SD}$  = 5 V,  $V_{REFH}$  = 17 V,  $V_{REFL}$  = 1V,  $R_L$  = 1.5 k $\Omega$  connected to ground, and  $C_L$  = 200pF, unless otherwise noted.



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## 7 Detailed Description

#### 7.1 Overview

The BUF20800-Q1 programmable voltage reference allows fast, easy adjustment of 18 programmable reference outputs and two channels for  $V_{COM}$  adjustment, each with 10-bit resolution. It offers very simple, time-efficient adjustment of the gamma reference and  $V_{COM}$  voltages. The BUF20800-Q1 is programmed through a high-speed, standard, two-wire interface. The BUF20800-Q1 features a double-register structure for each DAC channel to simplify the implementation of dynamic gamma control. This structure allows pre-loading of register data and rapid updating of all channels simultaneously.

Buffers 1-9 are able to swing to within 200mV of the positive supply rail, and to within 0.6V of the negative supply rail. Buffers 10-18 are able to swing to within 0.8V of the positive supply rail and to within 200mV of the negative supply rail.

The BUF20800-Q1 can be powered using an analog supply voltage from 7V to 18V, and a digital supply from 2V to 5.5V. The digital supply must be applied prior to or simultaneously with the analog supply to avoid excessive current and power consumption; damage to the device may occur if it is left connected only to the analog supply for extended periods of time. Figure 7 shows the power supply timing requirements.

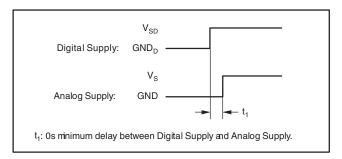


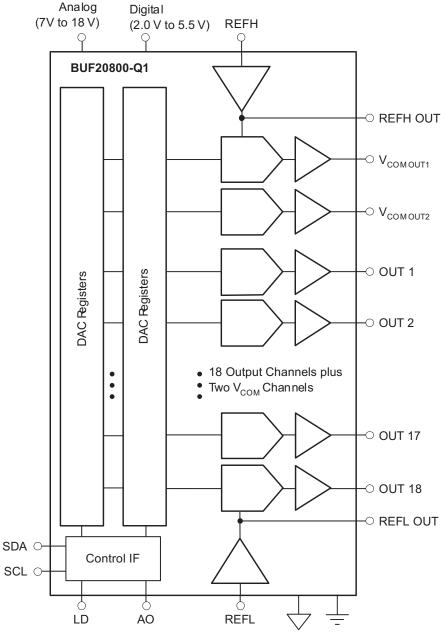
Figure 7. Power Supply Timing Requirements

shows the BUF20800-Q1 in a typical configuration. In this configuration, the BUF20800-Q1 device address is 74h. The output of each digital-to-analog converter (DAC) is immediately updated as soon as data are received in the corresponding register (LD = 0).

For maximum dynamic range, set  $V_{REFH} = V_S - 0.2 \text{ V}$  and  $V_{REFL} = GND + 0.2 \text{ V}$ .



#### 7.2 Functional Block Diagram



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## 7.3 Feature Description

#### 7.3.1 General-call Reset and Power-up

The BUF20800-Q1 responds to a General Call Reset, which is an address byte of 00h (0000 0000) followed by a data byte of 06h (0000 0110). The BUF20800-Q1 acknowledges both bytes. Upon receiving a General Call Reset, the BUF20800-Q1 performs a full internal reset, as though it had been powered off and then on. It always acknowledges the General Call address byte of 00h (0000 0000), but does not acknowledge any General Call data bytes other than 06h (0000 0110).

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#### **Feature Description (continued)**

The BUF20800-Q1 automatically performs a reset upon power up. As part of the reset, all outputs are set to  $(V_{REFH} - V_{REFL})/2$ . Other reset values are available as a custom modification—contact your TI representative for details.

The BUF20800-Q1 resets all outputs to  $(V_{REFH} - V_{REFL})/2$  after sending the device address, if a valid DAC address is sent with bits D7 to D5 set to '100'. If these bits are set to '010', only the DAC being addressed in this most significant byte (MSB) and the following least significant byte (LSB) will be reset.

#### 7.3.2 Output Voltage

Buffer output values are determined by the reference voltages (VREFH and VREFL) and the decimal value of the binary input code used to program that buffer. The value is calculated using Equation 1:

$$V_{\text{OUT}} = \left[\frac{V_{\text{REFH}} - V_{\text{REFL}}}{1024} \times \text{Decimal Value of Code}\right] + V_{\text{REFL}}$$
(1)

The valid voltage ranges for the reference voltages are:

$$4V \le V_{REFH} - V_S \le 0.2 \text{ V} \text{ and } 0.2 \text{ V} \le V_{REFL} \le V_S - 4 \text{ V}$$
 (2)

The BUF20800-Q1 outputs are capable of a full-scale voltage output change in typically 5  $\mu$ s—no intermediate steps are required.

#### 7.3.3 Output Latch

Updating the DAC register is not the same as updating the DAC output voltage, because the BUF20800-Q1 features a double-buffered register structure. There are three methods for latching transferred data from the storage registers into the DACs to update the DAC output voltages.

Method 1 requires externally setting the latch pin (LD) LOW, LD = LOW, which will update each DAC output voltage whenever its corresponding register is updated.

Method 2 externally sets LD = HIGH to allow all DAC output voltages to retain their values during data transfer and until LD = LOW, which will then simultaneously update the output voltages of all DACs to the new register values. Use this method to transfer a future data set in advance to prepare for a very fast output voltage update.

Method 3 uses software control. LD is maintained HIGH, and all DACs are updated when the master writes a 1 in bit 15 of any DAC register. The update will occur after receiving the 16-bit data for the currently-written register.

The General Call Reset and the power-up reset will update the DAC regardless of the state of the latch pin.

#### 7.3.4 Programmable VCOM

The  $V_{COM}$  channels of the BUF20800-Q1 can swing to 2V from the positive supply rail while sourcing 50 mA and to 1 V above the negative rail while sinking 50 mA (see Figure 4, typical characteristic *Output Voltage vs Output Current*). To store the gamma and the  $V_{COM}$  values, an external EEPROM is required. During power-up of the LCD panel, the timing controller can then read the EEPROM and load the values into the BUF20800-Q1 to generate the desired  $V_{COM}$  voltages, as illustrated in Figure 10 and Figure 8. The  $V_{COM}$  channels can be programmed independently from the gamma channels.



#### **Feature Description (continued)**

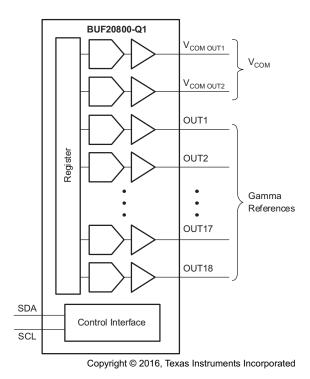


Figure 8. BUF20800-Q1 Used for Programmable V<sub>COM</sub>

#### 7.3.5 REFH and REFL Input range

Best performance and output swing range of the BUF20800-Q1 are achieved by applying REFH and REFL voltages that are slightly below the power-supply voltages. Most specifications have been tested at REFH =  $V_s$  – 200mV and REFL = GND + 200mV. The REFH internal buffer is designed to swing very closely to  $V_s$  and the REFL internal buffer to GND. However, there is a finite limit on how close they can swing before saturating. To avoid saturation of the internal REFH and REFL buffers, the REFH voltage should not be greater than  $V_s$  –100mV and REFL voltage should not be lower than GND + 100mV. Figure 9 shows the swing capability of the REFH and REFL buffers.

The other consideration when trying to maximize the output swing capability of the gamma buffers is the limitation in the swing range of output buffers (OUT1-18,  $V_{COM1}$ , and  $V_{COM2}$ ), which depends on the load current. A typical load in the LCD application is 5-10mA. For example, if OUT1 is sourcing 10mA, the swing is typically limited to about  $V_s$  - 200mV. The same applies to OUT18, which typically limits at GND + 200mV when sinking 10mA. An increase in output swing can only be achieved for much lighter loads. For example, a 3mA load typically allows the swing to be increased to approximately  $V_s$  - 100mV and GND + 100mV.

Connecting REFH directly to  $V_s$  and REFL directly to GND does not damage the BUF20800-Q1. As discussed above however, the output stages of the REFH and REFL buffers will saturate. This condition is not desirable and can result in a small error in the measured output voltages of OUT1-18,  $V_{COM1}$ , and  $V_{COM2}$ . As described above, this method of connecting REFH and REL does not help to maximize the output swing capability.

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#### **Feature Description (continued)**

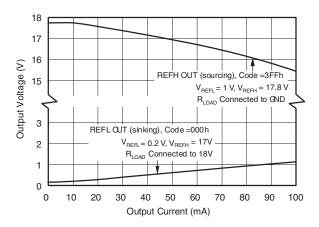


Figure 9. Reference Buffer Output Voltage vs Output Current

#### 7.4 Device Functional Modes

#### 7.4.1 Replacement of Traditional Gamma Buffer

Traditional gamma buffers rely on a resistor string (often using expensive 0.1% resistors) to set the gamma voltages. During development, the optimization of these gamma voltages can be time-consuming. Programming these gamma voltages with the BUF20800-Q1 can significantly reduce the time required for gamma voltage optimization. The final gamma values can be written into an external EEPROM to replace a traditional gamma buffer solution. During power-up of the LCD panel, the timing controller reads the EEPROM and loads the values into the BUF20800-Q1 to generate the desired gamma voltages. Figure 10a shows the traditional resistor string; Figure 10b shows the more efficient alternative method using the BUF20800-Q1.

BUF20800-Q1 uses the most advanced high-voltage CMOS process available today, which allows it to be competitive with traditional gamma buffers.

This technique offers significant advantages:

- · It shortens development time significantly.
- It allows demonstration of various gamma curves to LCD monitor makers by simply uploading a different set of gamma values.
- It allows simple adjustment of gamma curves during production to accommodate changes in the panel manufacturing process or end-customer requirements.
- It decreases cost and space.



#### **Device Functional Modes (continued)**

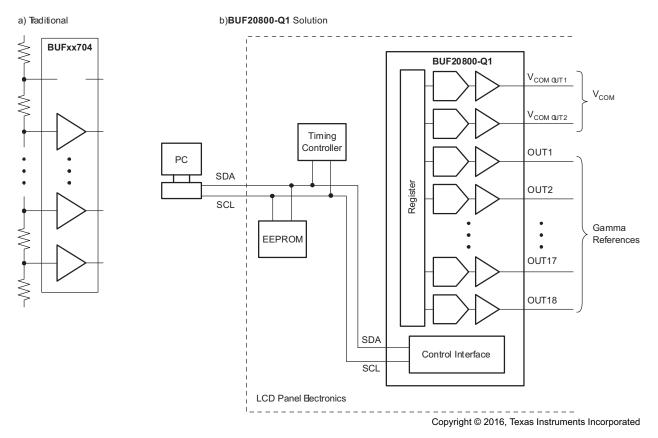


Figure 10. Replacement of the Traditional Gamma Buffer

#### 7.4.2 Dynamic Gamma Control

Dynamic gamma control is a technique used to improve the picture quality in LCD TV applications. The brightness in each picture frame is analyzed and the gamma curves are adjusted on a frame-by-frame basis. The gamma curves are typically updated during the short vertical blanking period in the video signal. Figure 11 shows a block diagram using the BUF20800-Q1 for dynamic gamma control and  $V_{COM}$  output.

The BUF20800-Q1 is ideally suited for rapidly changing the gamma curves because of its unique topology:

- double register input structure to the DAC;
- fast serial interface;
- simultaneous updating of all DACs by software. See the Read/Write Operations to write to all registers and the Output Latch sections.

The double register input structure saves programming time by allowing updated DAC values to be pre-loaded into the first register bank. Storage of this data can occur while a picture is still being displayed. Because the data are only stored into the first register bank, the DAC output values remain unchanged—the display is unaffected. During the vertical sync period, the DAC outputs (and therefore, the gamma voltages) can be quickly updated either by using an additional control line connected to the LD pin, or through software—writing a '1' in bit 15 of any DAC register. For the details on the operation of the double register input structure, see the Output Latch section.

**Example:** Update all 18 gamma registers simultaneously via software.

Step 1: Check if LD pin is placed in HIGH state.

Step 2: Write DAC Registers 1-18 with bit 15 always '0'.

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#### **Device Functional Modes (continued)**

**Step 3:** Write any DAC register a second time with identical data. Make sure that bit 15 is '1'. All DAC channels will be updated simultaneously after receiving the last bit of data. (Note: this step may be eliminated by setting bit 15 of DAC 18 to '1' in the previous step.)

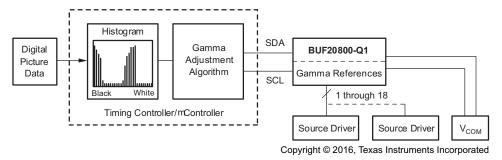


Figure 11. Dynamic Gamma Control

#### 7.5 Programming

#### 7.5.1 Two-wire Bus Overview

The BUF20800-Q1 communicates through an industry standard, two-wire interface to receive data in slave mode. This standard uses a two-wire, open-drain interface that supports multiple devices on a single bus. Bus lines are driven to a logic low level only. The device that initiates the communication is called a master, and the devices controlled by the master are slaves. The master generates the serial clock on the clock signal line (SCL), controls the bus access, and generates the START and STOP conditions.

To address a specific device, the master initiates a START condition by pulling the data signal line (SDA) from a HIGH to a LOW logic level while SCL is HIGH. All slaves on the bus shift in the slave address byte, with the last bit indicating whether a read or write operation is intended. During the 9th clock pulse, the slave being addressed responds to the master by generating an Acknowledge and pulling SDA LOW.

Data transfer is then initiated and eight bits of data are sent followed by an Acknowledge Bit. During data transfer, SDA must remain stable while SCL is HIGH. Any change in SDA while SCL is HIGH will be interpreted as a START or STOP condition.

Once all data has been transferred, the master generates a STOP condition indicated by pulling SDA from LOW to HIGH while SCL is HIGH.

The BUF20800-Q1 can act only as a slave device; therefore, it never drives SCL. SCL is only an input for the BUF20800-Q1. Table 1 and Table 2 summarize the address and command codes, respectively, for the BUF20800-Q1.

#### 7.5.2 Data Rates

The two-wire bus operates in one of three speed modes:

- Standard: allows a clock frequency of up to 100kHz;
- Fast: allows a clock frequency of up to 400kHz; and
- High-speed mode (also called Hs mode): allows a clock frequency of up to 3.4MHz.

The BUF20800-Q1 is fully compatible with all three modes. No special action is required to use the device in Standard or Fast modes, but High-speed mode must be activated. To activate High-speed mode, send a special address byte of 00001xxx, with SCL = 400kHz, following the START condition; xxx are bits unique to the Hscapable master, which can be any value. This byte is called the Hs master code. (Note that this is different from normal address bytes—the low bit does not indicate read/write status.) The BUF20800-Q1 will respond to the High-speed command regardless of the value of these last three bits. The BUF20800-Q1 will not acknowledge this byte; the communication protocol prohibits acknowledgment of the Hs master code. On receiving a master code, the BUF20800-Q1 will switch on its Hs mode filters, and communicate at up to 3.4MHz. Additional high-speed transfers may be initiated without resending the Hs mode byte by generating a repeat START without a STOP. The BUF20800-Q1 will switch out of Hs mode with the next STOP condition.



## **Programming (continued)**

#### 7.5.3 Read/Write Operations

The BUF20800-Q1 is able to read from a single DAC, or multiple DACs, or write to the register of a single DAC, or multiple DACs in a single communication transaction. DAC addresses begin with 0000 0000, which corresponds to DAC\_1, through 0001 0011, which corresponds to  $V_{COM}$  OUT2.

Write commands are performed by setting the read/write bit LOW. Setting the read/write bit HIGH will perform a read transaction.

#### 7.5.3.1 Writing

To write to a single DAC register

- 1. 1. Send a START condition on the bus.
- 2. Send the device address and read/write bit = LOW. The BUF20800-Q1 will acknowledge this byte.
- 3. Send a DAC address byte. Bits D7-D5 must be set to 0. Bits D4-D0 are the DAC address. Only DAC addresses 00000 to 10011 are valid and will be acknowledged. Table 3 shows the DAC addresses.
- 4. Send two bytes of data for the specified DAC register. Begin by sending the most significant byte first (bits D15-D8, of which only bits D9 and D8 are used, and bits D15-D14 must not be 01), followed by the least significant byte (bits D7-D0). The register is updated after receiving the second byte.
- 5. Send a STOP condition on the bus

The BUF20800-Q1 will acknowledge each data byte. If the master terminates communication early by sending a STOP or START condition on the bus, the specified register will not be updated. Updating the DAC register is not the same as updating the DAC output voltage. See the Output Latch section.

The process of updating multiple DAC registers begins the same as when updating a single register. However, instead of sending a STOP condition after writing the addressed register, the master continues to send data for the next register. The BUF20800-Q1 automatically and sequentially steps through subsequent registers as additional data is sent. The process continues until all desired registers have been updated or a STOP condition is sent.

To write to multiple DAC registers:

- 1. 1. Send a START condition on the bus.
- 2. Send the device address and read/write bit = LOW. The BUF20800-Q1 will acknowledge this byte.
- Send either the DAC\_1 address byte to start at the first DAC, or send the address byte for whichever DAC will be the first in the sequence of DACs to be updated. The BUF20800-Q1 will begin with this DAC and step through subsequent DACs in sequential order.
- 4. Send the bytes of data; begin by sending the most significant byte (bits D15–D8, of which only bits D9 and D8 have meaning), followed by the least significant byte (bits D7–D0). The first two bytes are for the DAC addressed in step 3 above. Its register is automatically updated after receiving the second byte. The next two bytes are for the following DAC. That DAC register is updated after receiving the fourth byte. This process continues until the registers of all following DACs have been updated.
- 5. Send a STOP condition on the bus.

The BUF20800-Q1 will acknowledge each byte. To terminate communication, send a STOP or START condition on the bus. Only DAC registers that have received both bytes of data will be updated.

Product Folder Links: BUF20800-Q1



#### **Programming (continued)**

#### 7.5.3.2 Reading

Reading a DAC register will return the data stored in the DAC. This data can differ from the data stored in the DAC register. See the Output Latch section.

#### To read the DAC value:

- 1. Send a START condition on the bus.
- 2. Send the device address and read/write bit = LOW. The BUF20800-Q1 will acknowledge this byte.
- 3. Send the DAC address byte. Bits D7-D5 must be set to 0; Bits D4-D0 are the DAC address. Only DAC addresses 00000 to 10011 are valid and will be acknowledged.
- 4. Send a START or STOP/START condition on the bus.
- 5. Send correct device address and read/write bit = HIGH. The BUF20800-Q1 will acknowledge this byte.
- 6. Receive two bytes of data. They are for the specified DAC. The first received byte is the most significant byte (bits D15–D8; only bits D9 and D8 have meaning); the next byte is the least significant byte (bits D7–D0).
- 7. Acknowledge after receiving the first byte.
- 8. Do not acknowledge the second byte to end the read transaction.

Communication may be terminated by sending a premature STOP or START condition on the bus, or by not sending the acknowledge.

#### To Read Multiple DACs:

- 1. Send a START condition on the bus.
- 2. Send the device address and read/write bit = LOW. The BUF20800-Q1 will acknowledge this byte.
- Send either the DAC\_1 address byte to start at the first DAC, or send the address byte for whichever DAC will be the first in the sequence of DACs to be read. The BUF20800-Q1 will begin with this DAC and step through subsequent DACs in sequential order.
- 4. Send a START or STOP/START condition on the bus.
- 5. Send correct device address and read/write bit = HIGH. The BUF20800-Q1 will acknowledge this byte.
- 6. Receive two bytes of data. They are for the specified DAC. The first received byte is the most significant byte (bits D15–D8, only bits D9 and D8 have meaning); the next byte is the least significant byte (bits D7–D0).
- 7. Acknowledge after receiving each byte of data except for the last byte. The acknowledge bit of the last byte should be HIGH to end the read operation.
- 8. When all desired DACs have been read, send a STOP or repeated START condition on the bus.

Communication may be terminated by sending a premature STOP or START condition on the bus, or by not sending the acknowledge.

Product Folder Links: BUF20800-Q1



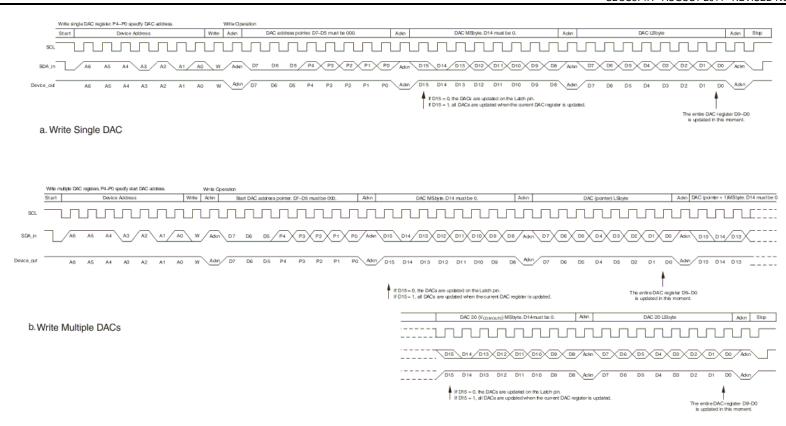


Figure 12. Timing Diagram for Write DAC Register

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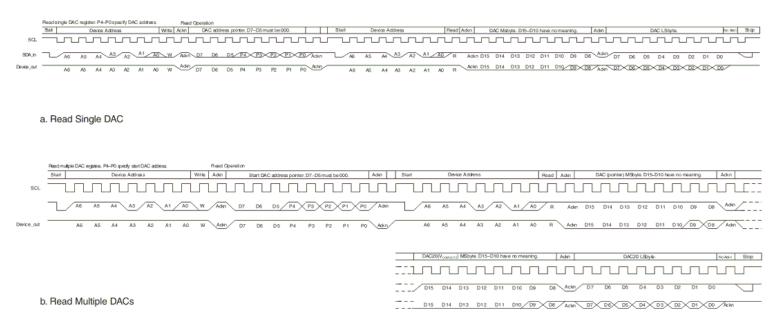


Figure 13. Timing Diagram for Read DAC Register

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## 7.5.4 Register Maps

#### 7.5.4.1 Addressing the BUF20800-Q1

The address of the BUF20800-Q1 is 111010x, where x is the state of the A0 pin. When the A0 pin is LOW, the device will acknowledge on address 74h (1110100). If the A0 pin is HIGH, the device will acknowledge on address 75h (1110101).

Other valid addresses are possible through a simple mask change. Contact your TI representative for information.

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Table 1. Quick-Reference Table of BUF20800-Q1 Addresses

DEVICE/COMPONENT	
BUF20800-Q1 Address:	ADDRESS
A0 pin is LOW (device acknowledges on address 74h)	1110100
A0 pin is HIGH (device acknowledges on address 75h)	1110101

**Table 2. Quick-Reference Table of Command Codes** 

COMMAND	CODE	
General Call Reset	Address byte of 00h followed by a data byte of 06h.	
High-Speed Mode	00001xxx, with SCL ≤ 400kHz; where xxx are bits unique to the Hs-capable master. This byte is called the Hs master code.	

## 7.5.5 Registers

Table 3. DAC Addresses

DAC	ADDRESS
DAC_1	0000 0000
DAC_2	0000 0001
DAC_3	0000 0010
DAC_4	0000 0011
DAC_5	0000 0100
DAC_6	0000 0101
DAC_7	0000 0110
DAC_8	0000 0111
DAC_9	0000 1000
DAC_10	0000 1001
DAC_11	0000 1010
DAC_12	0000 1011
DAC_13	0000 1100
DAC_14	0000 1101
DAC_15	0000 1110
DAC_16	0000 1111
DAC_17	0001 0000
DAC_18	0001 0001
V <sub>COM</sub> OUT1	0001 0010
V <sub>COM</sub> OUT2	0001 0011

Product Folder Links: BUF20800-Q1

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## 8 Application and Implementation

#### **NOTE**

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

#### 8.1 Application Information

The BUF20800-Q1 device was designed to provide 18 programmable outputs for gamma correction for the source driver IC and two VCOM channels for the common plane in LCD display applications.

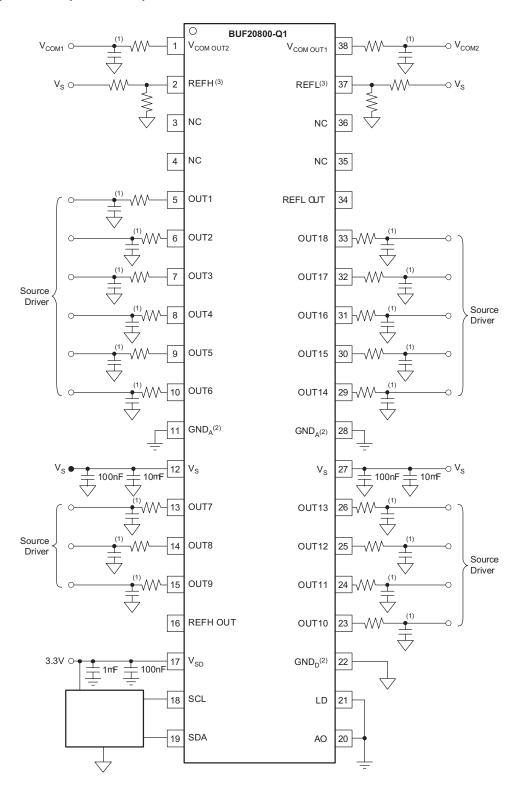
#### 8.2 Typical Application

Figure 14 shows a typical application circuit for the BUF20800-Q1 device.

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# TEXAS INSTRUMENTS

## **Typical Application (continued)**



- (1) RC combination optional.
- (2)  $\mathsf{GND}_\mathsf{A}$  and  $\mathsf{GND}_\mathsf{D}$  must be connected together.
- (3) Connecting a capacitor to this node is not recommended.

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Figure 14. Typical Application Configuration



## **Typical Application (continued)**

#### 8.2.1 Design Requirements

Table 4 shows the design parameters for this design.

**Table 4. Design Requirements** 

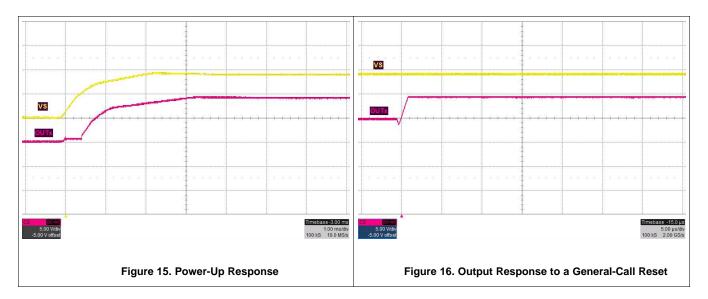
PARAMETER	SYMBOL	VALUE
Analog Input Supply Voltage	V <sub>S</sub>	18 V
Digital Input Supply Voltage	$V_{SD}$	5 V
REFH Input Voltage	$V_{REFH}$	17.8 V
REFL Input Voltage	$V_{REFL}$	0.2 V

#### 8.2.2 Detailed Design Procedure

#### 8.2.2.1 Input Capacitor Selection

For good input voltage filtering, low ESR ceramic capacitors are recommended. Connect a 10-µF capacitor in parallel to a 100-nF capacitor to all the analog input supply pins as shown in Figure 14. Connecting a 1-µF capacitor in parallel to a 1-nF capacitor is as well recommended at the digital input supply pin.

## 8.2.3 Application Curves

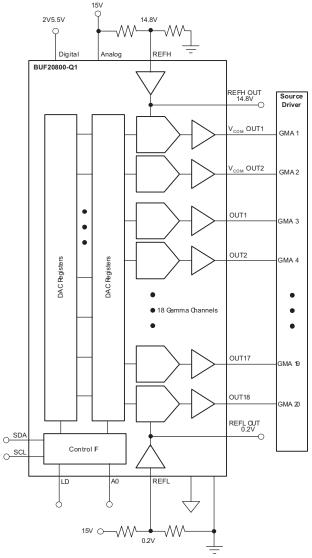


#### 8.2.4 Configuration for 20 Gamma Channels

The VCOM outputs can be used as additional gamma references in order to achieve two additional gamma channels (20 total). The VCOM outputs will behave the same as the OUT1-9 outputs when sourcing or sinking smaller currents (see Figure 4). The VCOM outputs are better able to swing to the positive rail than to the negative rail. Therefore, it is better to use the VCOM outputs for higher reference voltages, as shown in Figure 17.

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Figure 17. 20 Gamma Channel Solution - Two V<sub>COM</sub> Channels Used as Additional Gamma Channels

#### 8.2.5 Configuration for 22 Gamma Channels

In addition to the  $V_{COM}$  outputs, the REFH and REFL OUT outputs can also be used as fixed gamma references. The output voltage will be set by the REFH and REFL input voltages, respectively. Therefore, REFH OUT should be used for the highest voltage gamma reference, and REFL OUT for the lowest voltage gamma reference. A 22-channel solution can be created by using all 18 outputs, the two  $V_{COM}$  outputs, and both REFH/L OUT outputs for gamma references—see Figure 15. However, the REFH and REFL OUT buffers were designed to only drive light loads on the order of 5–10mA. Driving capacitive loads is not recommended with these buffers. In addition, the REFH and REFL buffers must not be allowed to saturate from sourcing/sinking too much current from REFH OUT or REFL OUT. Saturation of the REFH and REFL buffers results in errors in the voltages of OUT1–18 and  $V_{COM}$  OUT1–2. The BUF01900 can be used to provide a programmable  $V_{COM}$  output.



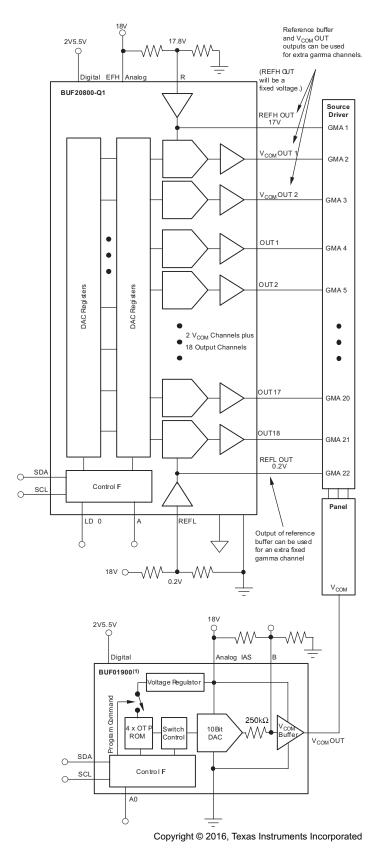


Figure 18. 22-Channel Gamma Solution



#### 8.2.6 The BUF20800-Q1 in Industrial Applications

The wide supply range, high output current, and very low cost make the BUF20800-Q1 attractive for a range of medium accuracy industrial applications such as programmable power supplies, multi-channel data-acquisition systems, data loggers, sensor excitation and linearization, power-supply generation, and other uses. Each DAC channel features 1LSB DNL and INL.

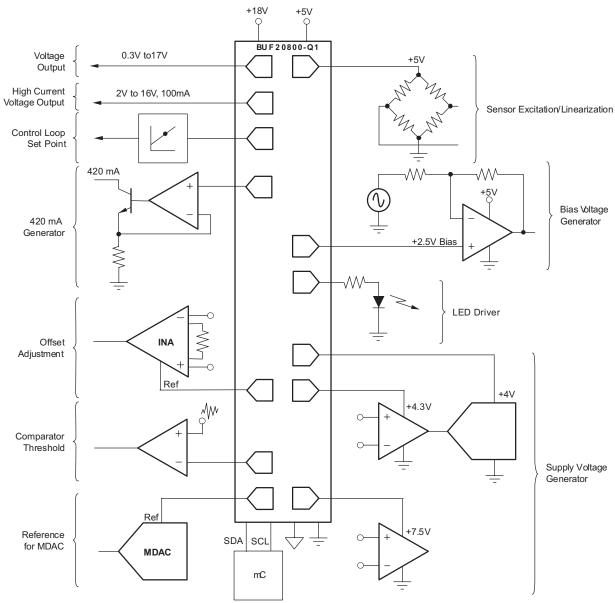
Many systems require different levels of biasing and power supply for various components as well as sensor excitation, control-loop set-points, voltage outputs, current outputs, and other functions. The BUF20800-Q1, with its 20 total programmable DAC channels, provides great flexibility to the entire system by allowing the designer to change all these parameters via software.

Figure 19 provides various ideas on how the BUF20800-Q1 can be used in applications. A micro-controller with two-wire serial interface controls the various DACs of the BUF20800-Q1. The BUF20800-Q1 can be used for:

- · sensor excitation
- · programmable bias/reference voltages
- variable power-supplies
- · high-current voltage output
- 4-20mA output
- · set-point generators for control loops

**NOTE:** The output voltages of the BUF20800-Q1 DACs will be set to  $(V_{REFH} - V_{REFL})/2$  at power-up or reset.





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Figure 19. Industrial Applications for the BUF20800-Q1



#### 8.2.7 Total TI Panel Solution

In addition to the BUF20800-Q1 programmable voltage reference, TI offers a complete set of ICs for the LCD panel market, including gamma correction buffers, various power-supply solutions, and audio power solutions. See Figure 20 for the total IC solution from TI.

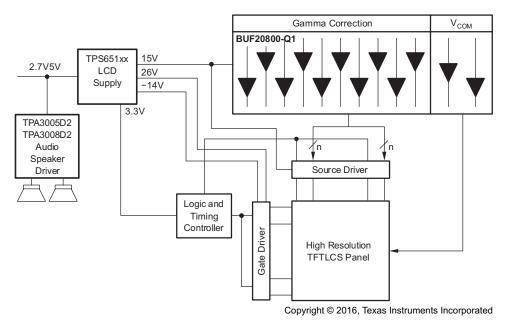


Figure 20. TI LCD Solution

## 9 Power Supply Recommendations

The device is designed to operate with an analog supply voltage from 7 V to 18 V, and a digital supply from 2 V to 5.5 V. The digital supply must be applied before the analog supply to avoid excessive current and power consumption, or possibly even damage to the device if left connected only to the analog supply for extended periods

of time.

The analog and digital supplies must be well regulated and the input capacitances shown in the application circuit in Figure 14 are recommended for typical applications.

#### 10 Layout

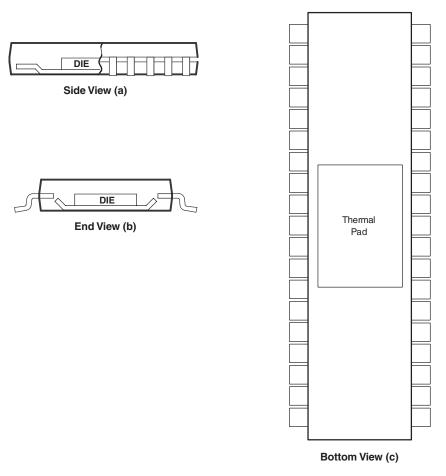
#### 10.1 Layout Guidelines

#### 10.1.1 General PowerPAD Design Considerations

The BUF20800-Q1 is available in a thermally-enhanced PowerPAD package. This package is constructed using a downset leadframe upon which the die is mounted, see Figure 21(a) and Figure 21(b). This arrangement results in the lead frame being exposed as a thermal pad on the underside of the package; see Figure 21(c). This thermal pad has direct thermal contact with the die; thus, excellent thermal performance is achieved by providing a good thermal path away from the thermal pad.



#### Layout Guidelines (continued)



The thermal pad is electrically isolated from all terminals in the package.

Figure 21. Views of Thermally-Enhanced DCP Package

The PowerPAD package allows for both assembly and thermal management in one manufacturing operation. During the surface-mount solder operation (when the leads are being soldered), the thermal pad must be soldered to a copper area underneath the package. Through the use of thermal paths within this copper area, heat can be conducted away from the package into either a ground plane or other heat-dissipating device. Soldering the PowerPAD to the printed circuit board (PCB) is always required, even with applications that have low power dissipation. This provides the necessary thermal and mechanical connection between the lead frame die pad and the PCB.

The PowerPAD must be connected to the most negative supply voltage on the device, GND<sub>A</sub> and GND<sub>D</sub>.

- 1. Prepare the PCB with a top-side etch pattern. There should be etching for the leads as well as etch for the thermal pad.
- 2. Place recommended holes in the area of the thermal pad. Ideal thermal land size and thermal via patterns for the HTSSOP-38 DCP package can be seen in the technical brief, PowerPAD Thermally-Enhanced Package (SLMA002), available for download at www.ti.com. These holes should be 13 mils in diameter. Keep them small, so that solder wicking through the holes is not a problem during reflow. An example thermal land pattern mechanical drawing is attached to the end of this data sheet.
- 3. Additional vias may be placed anywhere along the thermal plane outside of the thermal pad area. This helps dissipate the heat generated by the BUF20800-Q1 IC. These additional vias may be larger than the 13-mil diameter vias directly under the thermal pad. They can be larger because they are not in the thermal pad area to be soldered; thus, wicking is not a problem.

Product Folder Links: BUF20800-Q1

4. Connect all holes to the internal plane that is at the same voltage potential as the GND pins.

(3)



#### **Layout Guidelines (continued)**

- 5. When connecting these holes to the internal plane, do not use the typical web or spoke via connection methodology. Web connections have a high thermal resistance connection that is useful for slowing the heat transfer during soldering operations. This makes the soldering of vias that have plane connections easier. In this application, however, low thermal resistance is desired for the most efficient heat transfer. Therefore, the holes under the BUF20800-Q1 PowerPAD package should make their connection to the internal plane with a complete connection around the entire circumference of the plated-through hole.
- 6. The top-side solder mask should leave the terminals of the package and the thermal pad area with its twelve holes exposed. The bottom-side solder mask should cover the holes of the thermal pad area. This masking prevents solder from being pulled away from the thermal pad area during the reflow process.
- 7. Apply solder paste to the exposed thermal pad area and all of the IC terminals.
- 8. With these preparatory steps in place, the BUF20800-Q1 IC is simply placed in position and run through the solder reflow operation as any standard surface mount component. This preparation results in a properly installed part.

For a given  $\theta_{JA}$  (listed in the Electrical Characteristics table), the maximum power dissipation is shown in Figure 22, and is calculated by Equation 3:

$$P_{D} = \left(\frac{T_{MAX} - T_{A}}{\theta_{JA}}\right)$$

#### where

- P<sub>D</sub> = maximum power dissipation (W)
- T<sub>MAX</sub> = absolute maximum junction temperature (+125°C)
- T<sub>A</sub> = free-ambient air temperature (°C)

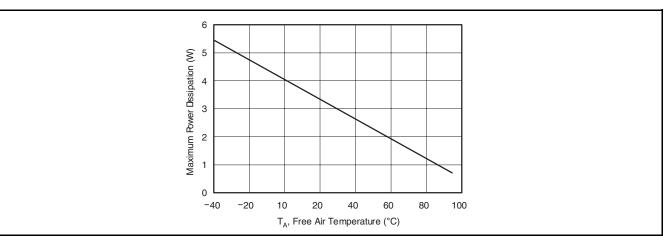


Figure 22. Maximum Power Dissipation vs Free-Air Temperature (with PowerPAD soldered down)

30



#### 10.2 Layout Example

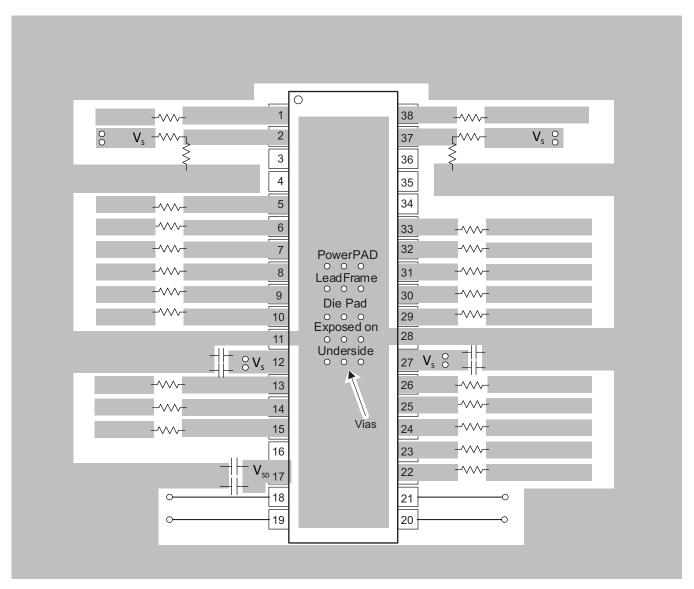


Figure 23. PCB Layout Example



## 11 Device and Documentation Support

#### 11.1 Documentation Support

#### 11.1.1 Related Documentation

For related documentation see the following:

- PowerPAD Thermally-Enhanced Package, SLMA002
- Driving Capacitive Loads with Gamma Buffers, SBOA134

#### 11.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

#### 11.3 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

#### 11.4 Trademarks

PowerPAD, E2E are trademarks of Texas Instruments.

#### 11.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 11.6 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.



## 12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: BUF20800-Q1



## PACKAGE OPTION ADDENDUM

28-Aug-2017

#### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	_	Pins	_	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
BUF20800ATDCPRQ1	ACTIVE	HTSSOP	DCP	38	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 105	BUF20800Q	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

#### OTHER QUALIFIED VERSIONS OF BUF20800-Q1:



## **PACKAGE OPTION ADDENDUM**

28-Aug-2017

• Catalog: BUF20800

www.ti.com

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

## PACKAGE MATERIALS INFORMATION

www.ti.com 28-Aug-2017

## TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
BUF20800ATDCPRQ1	HTSSOP	DCP	38	2000	330.0	16.4	6.9	10.2	1.8	12.0	16.0	Q1

www.ti.com 28-Aug-2017



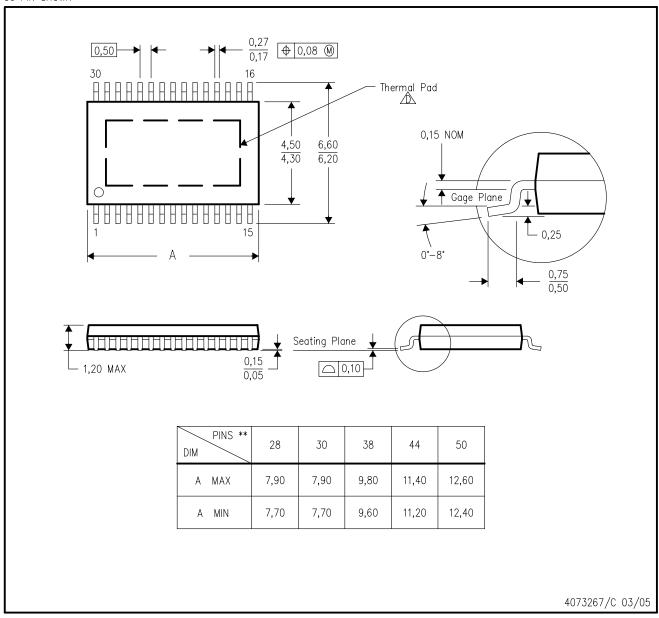
#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins SPQ		Length (mm) Width (mm)		Height (mm)	
BUF20800ATDCPRQ1	HTSSOP	DCP	38	2000	367.0	367.0	38.0	

# DCP (R-PDSO-G\*\*)

## PowerPAD™ PLASTIC SMALL-OUTLINE PACKAGE

30 PIN SHOWN



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protusions, mold flash not to exceed 0.15mm.
- This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com. See the product data sheet for details regarding the exposed thermal pad dimensions.
- E. Falls within JEDEC MO-153

PowerPAD is a trademark of Texas Instruments.



#### THERMAL PAD MECHANICAL DATA



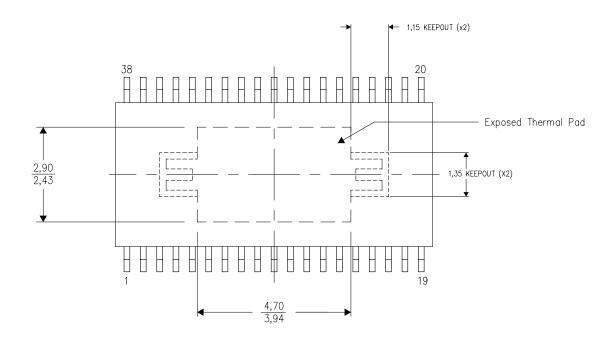
DCP (R-PDSO-G38)

#### THERMAL INFORMATION

This PowerPAD  $^{\text{TM}}$  package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.

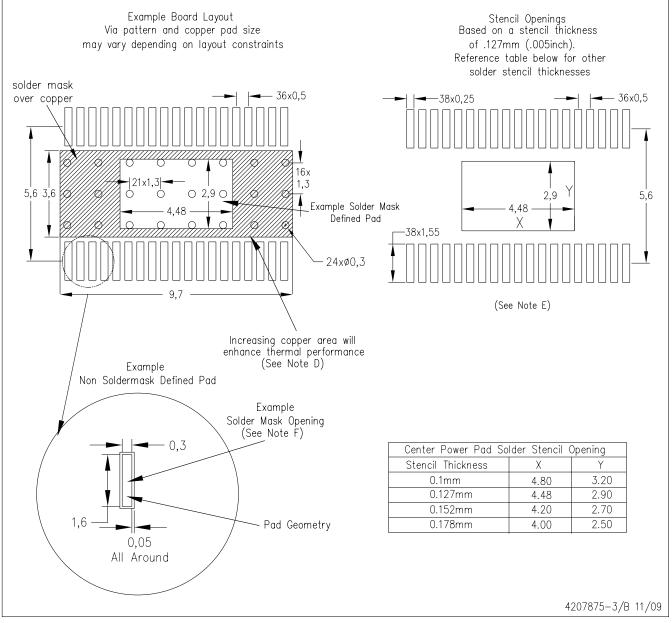


Top View

NOTE: All linear dimensions are in millimeters

Exposed Thermal Pad Dimensions

# DCP (R-PDSO-G38) PowerPAD™



#### NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <a href="http://www.ti.com">http://www.ti.com</a>. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.
- F. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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